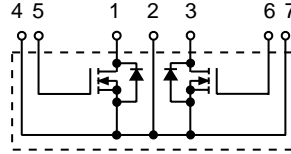


# Dual Power MOSFET Module

## VMK 90-02T2

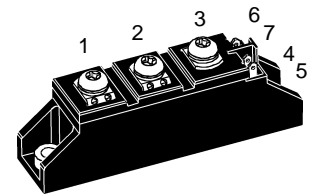
$V_{DSS} = 200\text{ V}$   
 $I_{D25} = 83\text{ A}$   
 $R_{DS(on)} = 25\text{ m}\Omega$

Common-Source connected  
N-Channel Enhancement Mode



| Symbol        | Test Conditions  | Maximum Ratings         |                  |
|---------------|--|-------------------------|------------------|
| $V_{DSS}$     | $T_J = 25^\circ\text{C}$ to $150^\circ\text{C}$  | 200                     | V                |
| $V_{DGR}$     | $T_J = 25^\circ\text{C}$ to $150^\circ\text{C}$ ; $R_{GS} = 6.8\text{ k}\Omega$            | 200                     | V                |
| $V_{GS}$      | Continuous   | $\pm 20$                | V                |
| $V_{GSM}$     | Transient  | $\pm 30$                | V                |
| $I_{D25}$     | $T_C = 25^\circ\text{C}$   | 83                      | A                |
| $I_{D80}$     | $T_C = 80^\circ\text{C}$   | 62                      | A                |
| $I_{DM}$      | $T_C = 25^\circ\text{C}$ , $t_p = 10\text{ }\mu\text{s}$ , pulse width limited by $T_{JM}$ | 330                     | A                |
| $P_D$         | $T_C = 25^\circ\text{C}$ , $T_J = 150^\circ\text{C}$ ,                                     | 380                     | W                |
| $T_J$         |  | -40 ... +150            | $^\circ\text{C}$ |
| $T_{JM}$      |  | 150                     | $^\circ\text{C}$ |
| $T_{stg}$     |  | -40 ... +125            | $^\circ\text{C}$ |
| $V_{ISOL}$    | 50/60 Hz   | $t = 1\text{ min}$      | 2500 V~          |
|               | $I_{ISOL} \leq 1\text{ mA}$  | $t = 1\text{ s}$        | 3000 V~          |
| $M_d$         | Mounting torque(M5 or 10-32 UNF)   | 2.5-4.0/22-35 Nm/lb.in. |                  |
|               | Terminal connection torque (M5)  | 2.5-4.0/22-35 Nm/lb.in. |                  |
| <b>Weight</b> | Typical including screws   | 90                      | g                |

TO-240 AA  
E 72873



1, 3 = Drain, 2 = Common Source  
5, 6 = Gate, 4, 7 = Kelvin Source

### Features

- Two MOSFET with common source
- International standard package JEDEC TO-240 AA
- Direct copper bonded  $\text{Al}_2\text{O}_3$  ceramic base plate
- Isolation voltage 3000 V~
- Low  $R_{DS(on)}$  HDMOS™ process
- Low package inductance for high speed switching
- Kelvin source contact
- Keyed twin plugs

### Applications

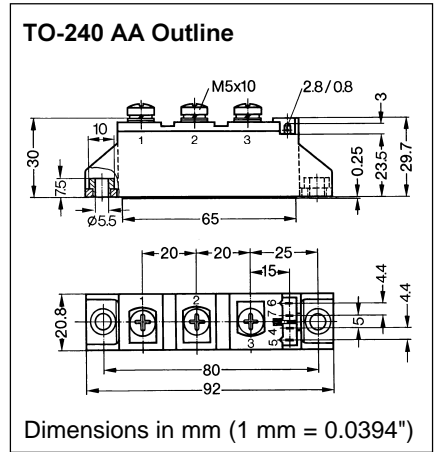
- Push-pull inverters
- Switched-mode and resonant-mode power supplies
- Uninterruptible power supplies (UPS)
- AC static switches

### Advantages

- Easy to mount with two screws
- Space and weight savings
- High power density
- Low losses

| Symbol       | Test Conditions  | Characteristic Values<br>( $T_J = 25^\circ\text{C}$ , unless otherwise specified) |      |                   |
|--------------|--|---|------|-------------------|
|              |  | min.  | typ. | max.              |
| $V_{DSS}$    | $V_{GS} = 0\text{ V}$ , $I_D = 1\text{ mA}$  | 200   |      | V                 |
| $V_{GS(th)}$ | $V_{DS} = V_{GS}$ , $I_D = 3\text{ mA}$  | 2   |      | 4 V               |
| $I_{GSS}$    | $V_{GS} = \pm 20\text{ V DC}$ , $V_{DS} = 0$   |   |      | 500 nA            |
| $I_{DSS}$    | $V_{DS} = 0.8 \cdot V_{DSS}$ , $V_{GS} = 0\text{ V}$ , $T_J = 25^\circ\text{C}$<br>$V_{GS} = 0\text{ V}$ , $T_J = 125^\circ\text{C}$ |   |      | 400 $\mu\text{A}$ |
|              |  |   |      | 2 mA              |
| $R_{DS(on)}$ | $V_{GS} = 10\text{ V}$ , $I_D = 0.5 \cdot I_{D25}$<br>Pulse test, $t \leq 300\text{ }\mu\text{s}$ , duty cycle $d \leq 2\%$          |   |      | 25 m $\Omega$     |

| Symbol       | Test Conditions   | Characteristic Values<br>( $T_J = 25^\circ\text{C}$ , unless otherwise specified) |      |                |
|--------------|---|---|------|----------------|
|              |   | min.  | typ. | max.           |
| $g_{fs}$     | $V_{DS} = 10\text{ V}; I_D = 0.5 \cdot I_{D25}$ pulsed  |   | 60   | S              |
| $C_{iss}$    | } $V_{GS} = 0\text{ V}, V_{DS} = 25\text{ V}, f = 1\text{ MHz}$   |   | 9000 | 15000 pF       |
| $C_{oss}$    |   |   | 1600 | 4500 pF        |
| $C_{rss}$    |   |   | 600  | 1500 pF        |
| $t_{d(on)}$  | } $V_{GS} = 10\text{ V}, V_{DS} = 0.5 \cdot V_{DSS}, I_D = 0.5 \cdot I_{D25}$<br>$R_G = 1\ \Omega$ (External), resistive load |   |      | 70 ns          |
| $t_r$        |   |   |      | 80 ns          |
| $t_{d(off)}$ |   |   |      | 200 ns         |
| $t_f$        |   |   |      | 100 ns         |
| $Q_g$        | } $V_{GS} = 10\text{ V}, V_{DS} = 0.5 \cdot V_{DSS}, I_D = 0.5 \cdot I_{D25}$   |   | 380  | 450 nC         |
| $Q_{gs}$     |   |   | 70   | 110 nC         |
| $Q_{gd}$     |   |   | 190  | 230 nC         |
| $R_{thJC}$   |   |   |      | 0.33 K/W       |
| $R_{thJK}$   | with heat transfer paste  |   |      | 0.53 K/W       |
| $d_s$        | Creepage distance on surface  | 12.7  |      | mm             |
| $d_A$        | Strike distance through air   | 9.6   |      | mm             |
| $a$          | Max. allowable acceleration   |   | 50   | $\text{m/s}^2$ |



| Symbol   | Test Conditions  | Characteristic Values<br>( $T_J = 25^\circ\text{C}$ , unless otherwise specified) |      |        |
|----------|--|---|------|--------|
|          |  | min.  | typ. | max.   |
| $I_S$    | $V_{GS} = 0\text{ V}$  |   |      | 83 A   |
| $I_{SM}$ | Repetitive; pulse width limited by $T_{JM}$  |   |      | 330 A  |
| $V_{SD}$ | $I_F = I_S; V_{GS} = 0\text{ V},$<br>Pulse test, $t \leq 300\ \mu\text{s}$ , duty cycle $d \leq 2\%$ |   | 1.0  | 1.2 V  |
| $t_{rr}$ | $I_F = I_S, -di/dt = 100\text{ A}/\mu\text{s}, V_{DS} = 100\text{ V}, V_{GS} = 0\text{ V}$           |   | 400  | 750 ns |